NSN 5961-01-112-1827

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View Online at https://aerobasegroup.com/nsn/5961-01-112-1827 **Inclosure Material:** Metal **Overall Length:** 0.375 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 breakdown voltage, collector to emitter, sustained **Current Rating Per Characteristic:** 30.00 amperes source cutoff current **Power Rating Per Characteristic:** 200.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: